

NCE P-Channel Enhancement Mode Power MOSFET

Description

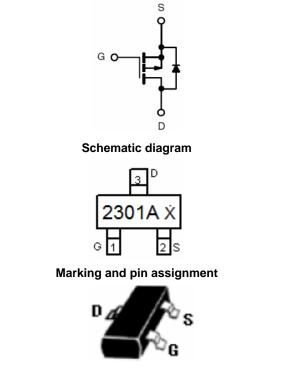
The NCE2301A uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

- $V_{DS} = -15V, I_D = -3.0A$ $R_{DS(ON)} < 70m\Omega @ V_{GS} = -2.5V$ $R_{DS(ON)} < 80m\Omega @ V_{GS} = -4.5V$
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- PWM applications
- Load switch
- Power management



SOT-23 top view

Package Marking and Ordering Information

V	<u> </u>				
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301A X	NCE2301A	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-15	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	ID	-3.0	A
Drain Current -Pulsed (Note 1)	I _{DM}	-15	A
Maximum Power Dissipation	PD	1	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

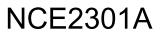
Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	125	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-15	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-15V,V _{GS} =0V	-	-	-1	μA







Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
Drain Course On State Desistance		V _{GS} =-4.5V, I _D =-2.5A	-	42	70	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =-2.5V, I_D =-2A	-	58	80	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-2A	5	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}	V _{DS} =-10V,V _{GS} =0V,	-	405	_	PF
Output Capacitance	Coss		-	112	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	89	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	tr	V _{DD} =-10V, R _L =2.9Ω V _{GS} =-4.5V,R _{GEN} =10Ω	-	35	-	nS
Turn-Off Delay Time	t _{d(off)}		-	30	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	V _{DS} =-10V,I _D =-2.5A,	-	9	-	nC
Gate-Source Charge	Q _{gs}		-	1.0	-	nC
Gate-Drain Charge	Q _{gd}	V_{GS} =-4.5V	-	2.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-3.0A	-	-	-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-3.0	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



NCE2301A



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Typical Electrical and Thermal Characteristics

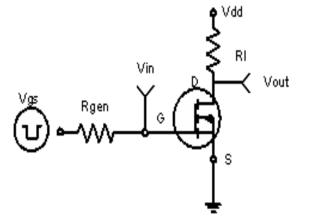
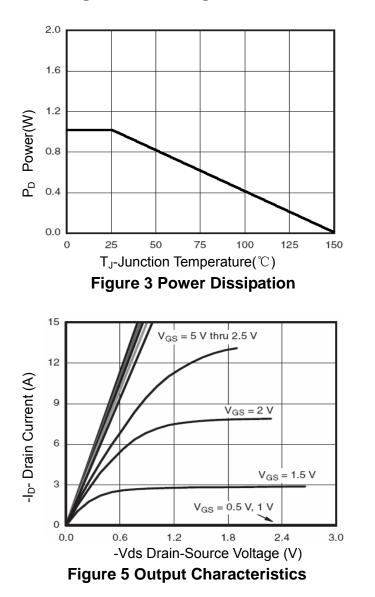
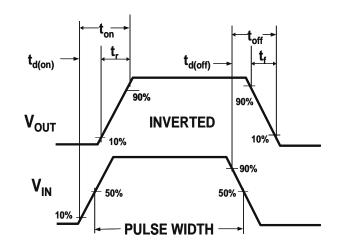
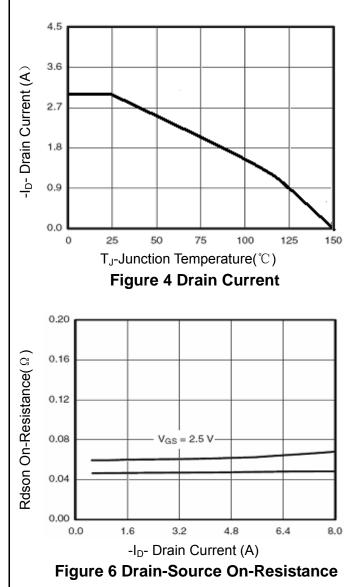


Figure 1:Switching Test Circuit





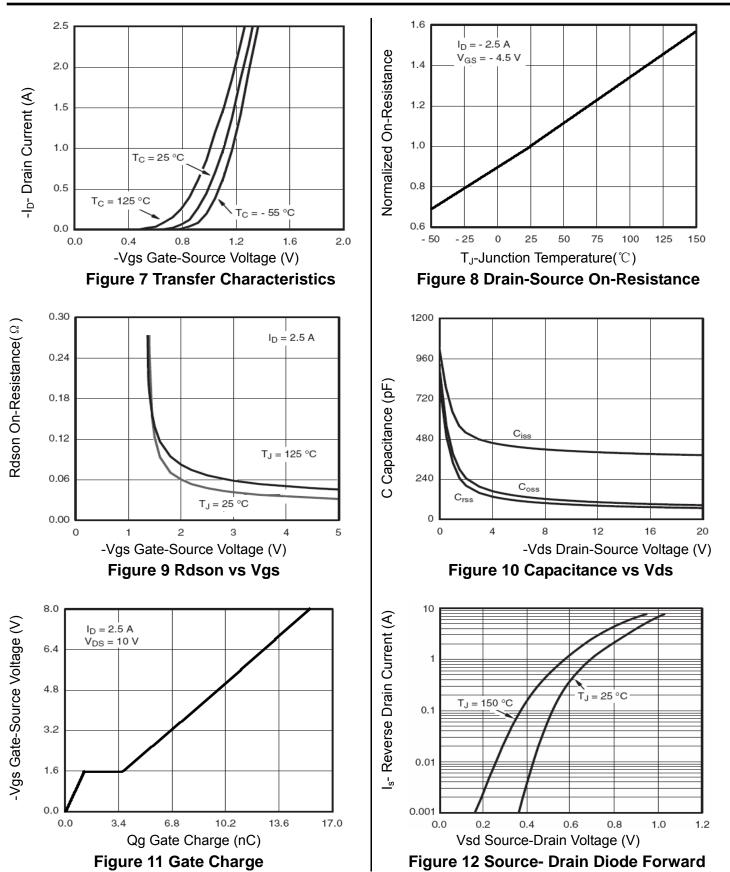








NCE2301A







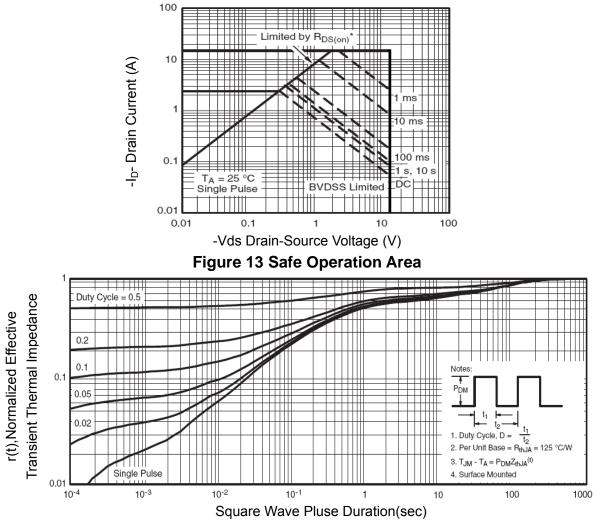
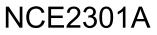


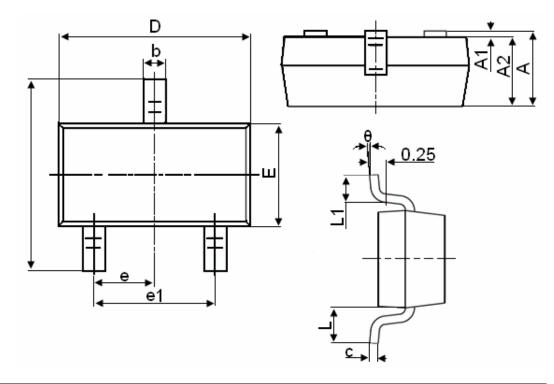
Figure 14 Normalized Maximum Transient Thermal Impedance







SOT-23 Package Information



Symbol		Dimensions in Millimeters	
Symbol	MIN.	MAX.	
A	0.900	1.150	
A1	0.000	0.100	
A2	0.900	1.050	
b	0.300	0.500	
с	0.080	0.150	
D	2.800	3.000	
E	1.200	1.400	
E1	2.250	2.550	
е	0.950TYP		
e1	1.800	2.000	
L		0.550REF	
L1	0.300	0.500	
θ	0°	8°	

Notes

1. All dimensions are in millimeters.

2. Tolerance ±0.10mm (4 mil) unless otherwise specified

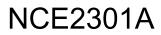
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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